

# Precision, Low Noise, High Stability Hermetic Voltage Reference

## FEATURES

- Hermetic 5mm × 5mm LCC Leadless Chip Carrier Package:
  - Insensitive to Humidity
  - Thermal Hysteresis: 8ppm (0°C to 70°C)
  - Thermal Hysteresis: 12ppm (–40°C to 85°C)
- Low Drift: 5ppm/°C Max
- High Accuracy: ±0.10% Max
- Low Noise: <1ppm Peak-to-Peak (0.1Hz to 10Hz)
- Low Long Term Drift
  - 12ppm at 1000Hr
  - 18ppm at 3000Hr
- Sinks 10mA, Sources 15mA
- Wide Supply Range to 40V
- 8-Pin (5mm × 5mm) LS8 Package

## APPLICATIONS

- Instrumentation and Test Equipment
- High Resolution Data Acquisition Systems
- A/D and D/A Converters
- Precision Regulators
- Precision Scales
- Digital Voltmeters

## DESCRIPTION

The **LT<sup>®</sup>1027LS8** is a precision reference that combines low drift and noise with excellent long-term stability and high output accuracy. The reference output will source up to 15mA and sink up to 10mA, and remain constant with input voltage variations.

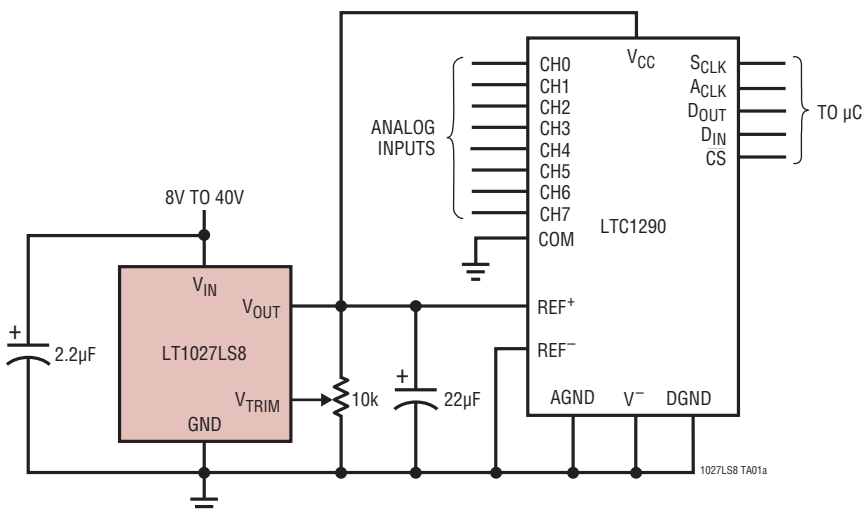
The hermetic package provides outstanding humidity and thermal hysteresis performance. The LT1027LS8 is only 5mm × 5mm × 1.5mm, offering an alternative to large through-hole metal can voltage references, such as the industry standard LT1021. The LT1027LS8 offers similar performance to the LT1027, with additional stability from the hermetic package.

LT1027LS8 is based on a buried Zener diode structure, which enables temperature and time stability, and extremely low noise performance of < 1ppm peak-to-peak. The LT1027LS8 operates on a supply voltage from 8V up to 40V. The subsurface Zener exhibits better time stability than even the best bandgap reference, and the hermetic package maintains that stability over a wide range of environmental conditions.

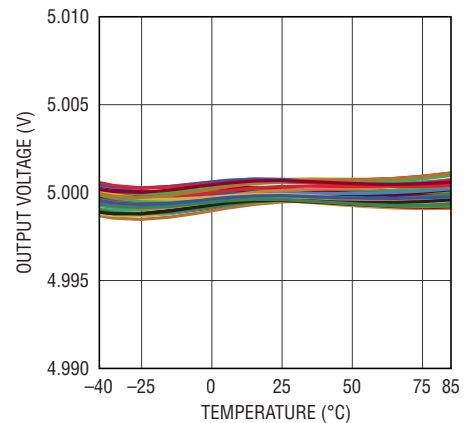
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## TYPICAL APPLICATION

Supplying  $V_{REF}$  and  $V_{CC}$  to the LTC1290 12-Bit ADC



Output Voltage Temperature Drift



1027LS8 TA01b

1027Is8f

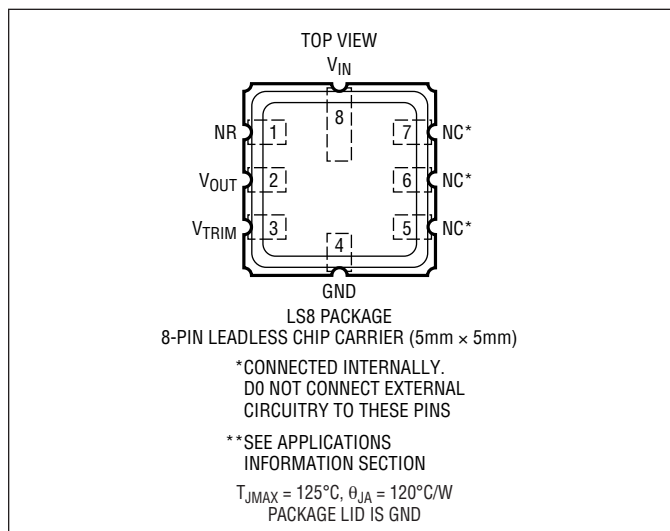
# LT1027LS8

## ABSOLUTE MAXIMUM RATINGS

(Note 1)

Input Voltage.....	40V
Input/Output Voltage Differential .....	35V
Output to Ground Voltage .....	7V
$V_{TRIM}$ to Ground Voltage	
Positive.....	5V
Negative.....	-0.3V
Output Short-Circuit Duration	
$V_{IN} > 20V$ .....	10 sec
$V_{IN} \leq 20V$ .....	Indefinite
Operating Temperature Range	
LT1027C.....	0°C to 70°C
LT1027I.....	-40°C to 85°C
Storage Temperature Range .....	-65°C to 150°C

## PIN CONFIGURATION



## ORDER INFORMATION

(<http://www.linear.com/product/LT1027LS8#orderinfo>)

LEAD FREE FINISH	PART MARKING	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT1027DCLS8-5#PBF	10275	8-Lead Ceramic LCC 5mm x 5mm	0°C to 70°C
LT1027DILS8-5#PBF	10275	8-Lead Ceramic LCC 5mm x 5mm	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandree/>. Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.

# ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^\circ\text{C}$ .  $V_{IN} = 10\text{V}$ ,  $I_{LOAD} = 0\text{A}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$V_{OUT}$	Output Voltage (Note 2)		4.995	5.000	5.005	V
$TCV_{OUT}$	Output Voltage Temperature Coefficient (Note 3)		●	2	5	ppm/ $^\circ\text{C}$
	Line Regulation (Note 4)	$8\text{V} \leq V_{IN} \leq 10\text{V}$	●	6	12	ppm/V
		$10\text{V} \leq V_{IN} \leq 40\text{V}$	●	3	6	ppm/V
	Load Regulation (Notes 4, 6)	Sourcing Current $0 \leq I_{OUT} \leq 15\text{mA}$ , $0^\circ\text{C}$ to $85^\circ\text{C}$ $0 \leq I_{OUT} \leq 5\text{mA}$ , $-40^\circ\text{C}$	●	-8 -10 -10	8 15 15	ppm/mA ppm/mA ppm/mA
		Sinking Current $0 \leq I_{OUT} \leq 10\text{mA}$ $0^\circ\text{C}$ to $85^\circ\text{C}$ $-40^\circ\text{C}$	●	30	120 160	ppm/mA ppm/mA
	Supply Current		●	2.2	3.1 3.5	mA mA
	$V_{TRIM}$ Adjust Range		●	$\pm 30$	$\pm 50$	mV
$e_n$	Output Noise (Note 5)	$0.1\text{Hz} \leq f \leq 10\text{Hz}$		3		$\mu\text{V}_{P-P}$
		$10\text{Hz} \leq f \leq 1\text{kHz}$		2.0	6.0	$\mu\text{V}_{RMS}$
	Long-Term Stability of Output Voltage (Note 7)	$\Delta t = \text{First } 1000\text{Hrs}$ $\Delta t = \text{First } 3000\text{Hrs}$		12 18		ppm ppm
	Temperature Hysteresis of Output (Note 8)	$\Delta T = \pm 25^\circ\text{C}$ $\Delta T = 0^\circ\text{C}$ to $70^\circ\text{C}$ $\Delta T = -40^\circ\text{C}$ to $85^\circ\text{C}$		6 8 12		ppm ppm ppm

**Note 1:** Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

**Note 2:** Output voltage is measured immediately after turn-on. Changes due to chip warm-up are typically less than 0.005%.

**Note 3:** Temperature coefficient is measured by dividing the change in output voltage over the temperature range by the change in temperature.

**Note 4:** Line and load regulation are measured on a pulse basis. Output changes due to die temperature change must be taken into account separately.

**Note 5:** RMS noise is measured with an 8-pole bandpass filter with a center frequency of 30Hz and a Q of 1.5. The filter output is then rectified and integrated for a fixed time period, resulting in an average, as opposed to RMS voltage. A correction factor is used to convert average to RMS. This value is then used to obtain RMS noise voltage in the 10Hz to 1000Hz frequency band. This test also screens for low frequency "popcorn" noise within the bandwidth of the filter.

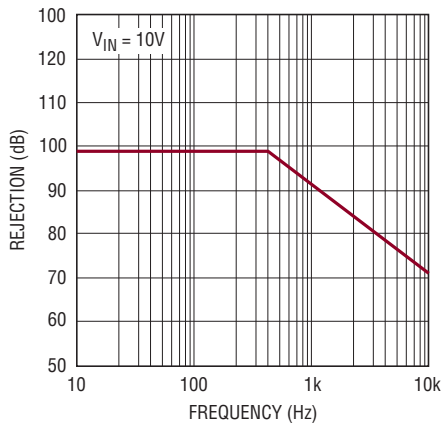
**Note 6:** Devices typically exhibit a slight negative DC output impedance of  $-0.015\Omega$ . This compensates for PC trace resistance, improving regulation at the load.

**Note 7:** Long-term stability typically has a logarithmic characteristic and therefore, changes after 1000 hours tend to be much smaller than before that time. Total drift in the second thousand hours is normally less than one third that of the first thousand hours, with a continuing trend toward reduced drift with time. Significant improvement in long-term drift can be realized by preconditioning the IC with a 100-200 hour,  $125^\circ\text{C}$  burn in. Long term stability will also be affected by differential stresses between the IC and the board material created during board assembly. Temperature cycling and baking of completed boards is often used to reduce these stresses in critical applications.

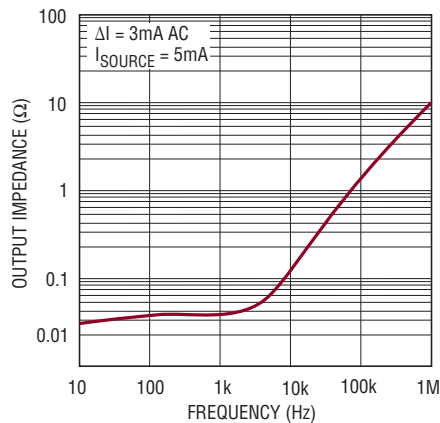
**Note 8:** Hysteresis in output voltage is created by package stress that differs depending on whether the IC was previously at a higher or lower temperature. Output voltage is always measured at  $25^\circ\text{C}$ , but the IC is cycled to high or low temperature before successive measurements. Hysteresis is roughly proportional to the square of temperature change. Hysteresis is not normally a problem for operational temperature excursions, but can be significant in critical narrow temperature range applications where the instrument might be stored at high or low temperatures. Hysteresis measurements are preconditioned by one temperature cycle.

## TYPICAL PERFORMANCE CHARACTERISTICS

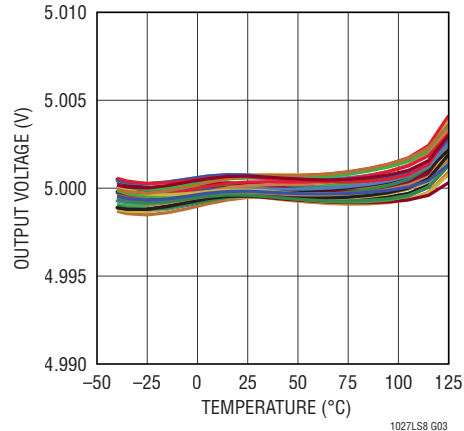
**Ripple Rejection**



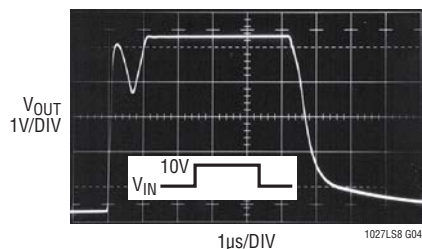
**Output Impedance vs Frequency**



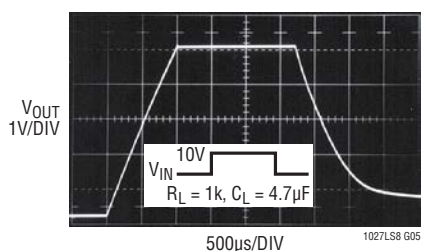
**Output Voltage Temperature Drift**



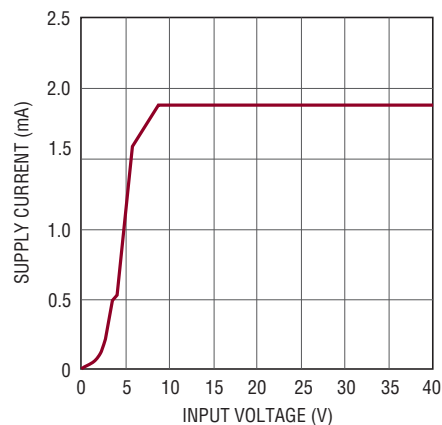
**Start-Up and Turn-Off (No Load)**



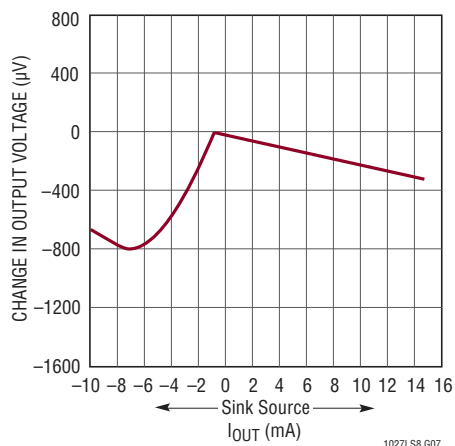
**Start-Up and Turn-Off**



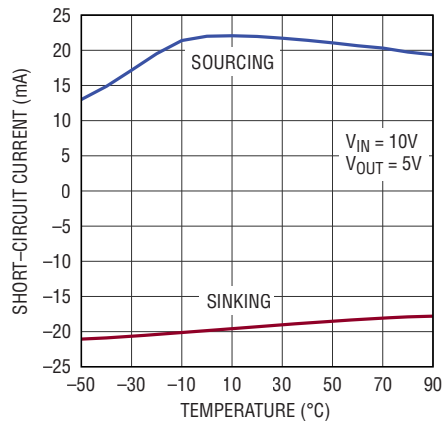
**Quiescent Current**



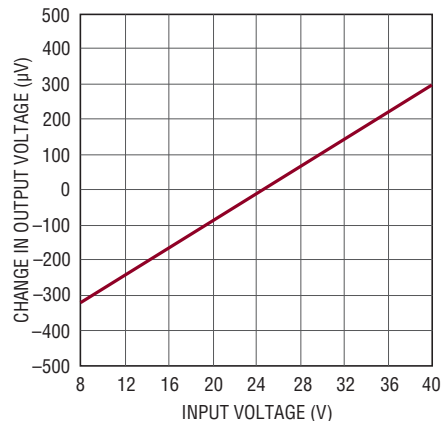
**Load Regulation**



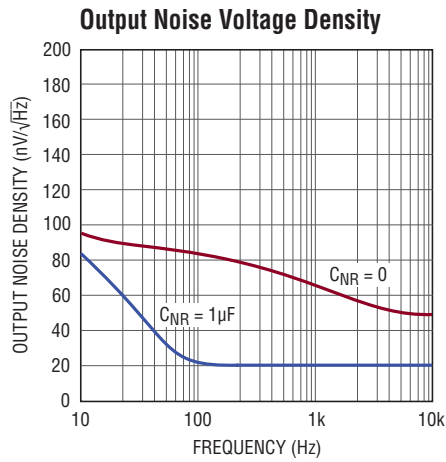
**Output Short-Circuit Current vs Temperature**



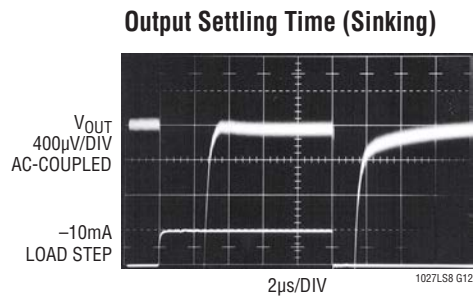
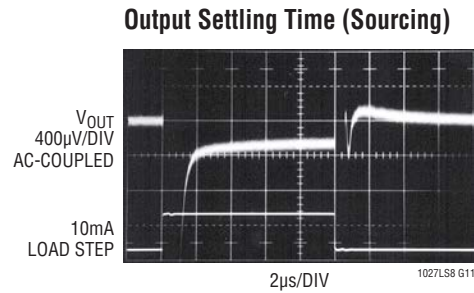
**Line Regulation**



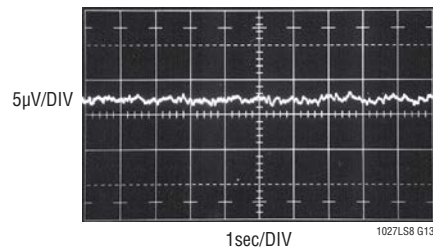
# TYPICAL PERFORMANCE CHARACTERISTICS



1027LS8 G10



**0.1Hz to 10Hz Output Noise  
Filtering = 1 Zero at 0.1Hz  
2 Poles at 10Hz**



## PIN FUNCTIONS

**NR (Pin 1):** Noise Reduction Pin. Add a capacitor to reduce wideband noise. See the Applications Information section for details.

**V<sub>OUT</sub> (Pin 2):** Output Voltage. See the Applications Information section for details regarding DC and capacitive loading and stability.

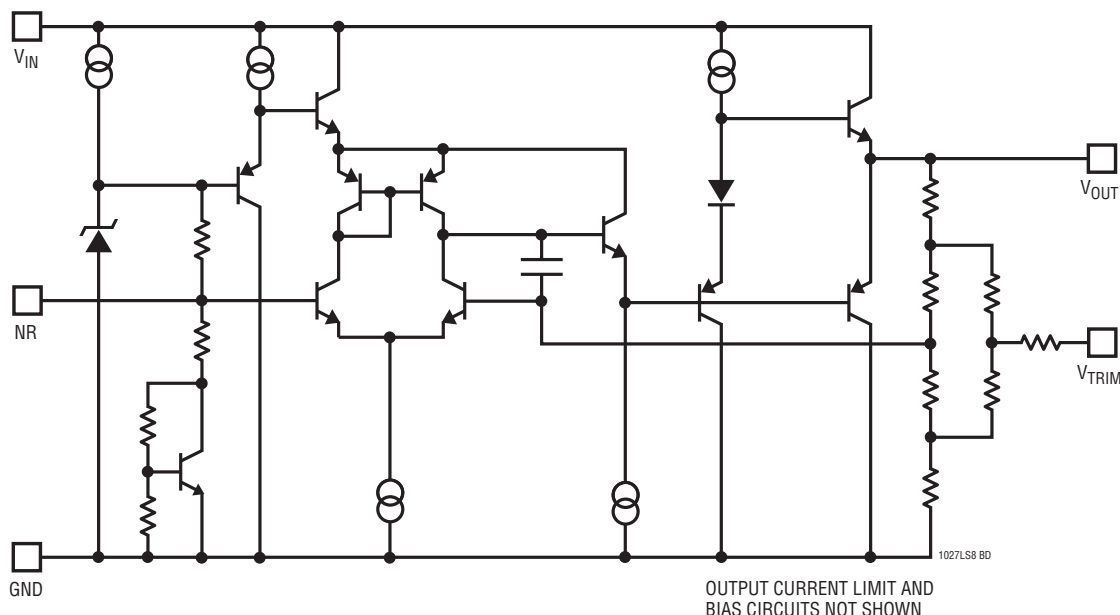
**V<sub>TRIM</sub> (Pin 3):** Allows adjustment of output voltage. See the Applications Information section for details.

**GND (Pin 4):** Device Ground. See the Applications Information section for recommended connection methods.

**NC (Pins 5, 6, 7):** Connected internally, do not connect.

**V<sub>IN</sub> (Pin 8):** Power Supply. Bypass with 0.1μF (or larger) capacitor to ground.

## BLOCK DIAGRAM



## APPLICATIONS INFORMATION

### Effect of Reference Drift on System Accuracy

A large portion of the temperature drift error budget in many systems is the system reference voltage. Figure 1 indicates the maximum temperature coefficient allowable if the reference is to contribute no more than 0.5LSB error to the overall system performance. The example shown is a 12-bit system designed to operate over a temperature range from 25°C to 65°C. Assuming the system calibration is performed at 25°C, the temperature span is 40°C. It can be seen from the graph that the temperature coefficient of the reference must be no worse than 6ppm/°C if it is to contribute less than 1LSB error. For this reason, the LT1027LS8 has been optimized for low drift.

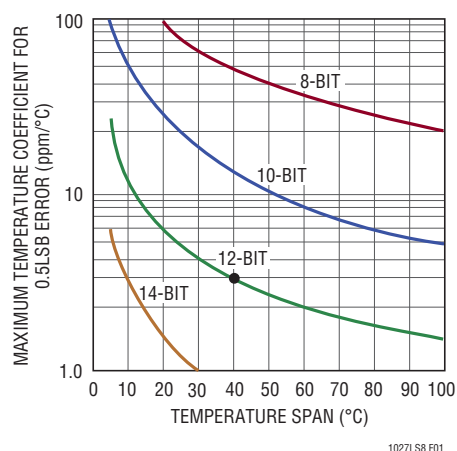


Figure 1. Maximum Allowable Reference Drift

### Trimming Output Voltage

The LT1027LS8 has an adjustment pin for trimming output voltage. The impedance of the  $V_{TRIM}$  pin is approximately 20k $\Omega$  with an open-circuit voltage of 2.5V. A  $\pm 30$ mV guaranteed trim range is achievable by tying the  $V_{TRIM}$  pin to the wiper of a 10k potentiometer connecting between the output and ground. Trimming output voltage does not affect the TC of the device.

### Noise Reduction

The positive input of the internal scaling amplifier is brought out as the Noise Reduction (NR) pin. Connecting a 1 $\mu$ F Mylar capacitor between this pin and ground will reduce the wideband noise of the LT1027LS8 from 2.0 $\mu$ V<sub>RMS</sub> to approximately 1.2 $\mu$ V<sub>RMS</sub> in a 10Hz to 1kHz bandwidth. Transient response is not affected by this capacitor. Start-up settling time will increase to several milliseconds due to the 7k $\Omega$  impedance looking into the NR pin. The capacitor *must* be a low leakage type. Electrolytics are *not* suitable for this application. Just 100nA leakage current will result in a 150ppm error in output voltage. This pin is the most sensitive pin on the device. For maximum protection a guard ring is recommended. The ring should be driven from a resistive divider from  $V_{OUT}$  set to 4.4V (the open-circuit voltage on the NR pin).

### Transient Response

The LT1027LS8 has been optimized for transient response. Settling time is under 2 $\mu$ s when an AC-coupled 10mA load transient is applied to the output. The LT1027LS8 achieves fast settling by using a class B NPN/PNP output stage. When sinking current, the device may oscillate with capacitive loads greater than 100pF. The LT1027LS8 is stable with all capacitive loads when at no DC load or when sourcing current, although for best settling time either no output bypass capacitor or a 4.7 $\mu$ F tantalum unit is recommended. An 0.1 $\mu$ F ceramic output capacitor will *maximize output ringing* and is *not* recommended.

### Kelvin Connections

Although the LT1027LS8 does not have true force-sense capability, proper hook-up can improve line loss and ground loop problems significantly. Since the ground pin of the LT1027LS8 carries only 2mA, it can be used as a low-side sense line, greatly reducing ground loop problems on the low side of the reference. The  $V_{OUT}$  pin should be close to the load or connected via a heavy trace as the resistance of this trace directly affects load regulation. It is important to remember that a 1.22mV drop due to trace resistance is equivalent to a 1LSB error in a 5V<sub>FS</sub>, 12-bit system.

## APPLICATIONS INFORMATION

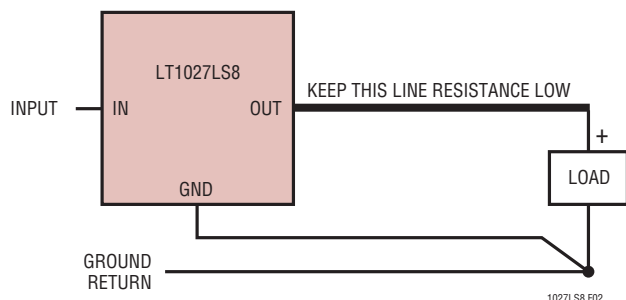


Figure 2. Standard Connection

The circuits in Figure 2 and Figure 3 illustrate proper connections to minimize errors due to ground loops and line losses. Losses in the output lead can be further reduced by adding a PNP boost transistor if load current is 5mA or higher. R2 can be added to further reduce current in the output sense lead.

### Long-Term Drift

Long-term drift cannot be extrapolated from accelerated high temperature testing. This erroneous technique gives drift numbers that are wildly optimistic. The only way long-term drift can be determined is to measure it over the time interval of interest.

The LT1027LS8 long-term drift data was collected on 80 parts that were soldered into printed circuit boards similar to a *real world* application. The boards were then placed into a constant temperature oven with a  $T_A = 35^\circ\text{C}$ , their outputs were scanned regularly and measured with an 8.5 digit DVM. Typical long-term drift is illustrated in Figure 4.

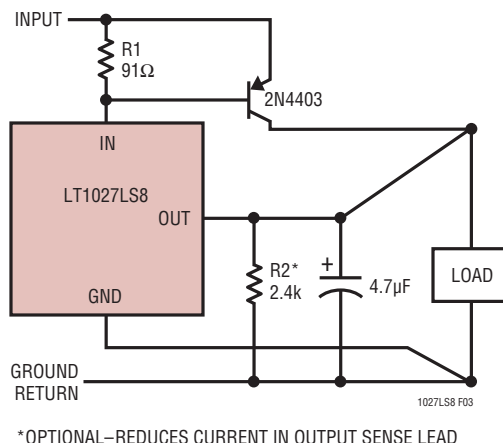


Figure 3. Driving Higher Load Currents

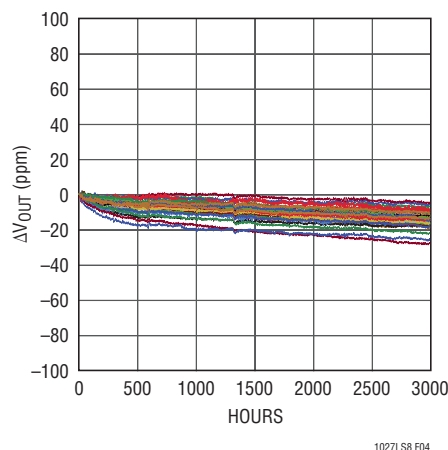


Figure 4. Long-Term Drift



## APPLICATIONS INFORMATION

### Hysteresis

Thermal hysteresis is a measure of change of output voltage as a result of temperature cycling. Figure 5, Figure 6 and Figure 7 illustrate the typical hysteresis based on data taken from the LT1027LS8. A proprietary design technique minimizes thermal hysteresis.

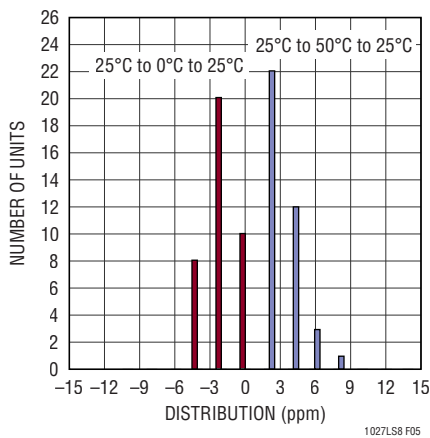


Figure 5. Thermal Hysteresis Plot, 0°C to 50°C

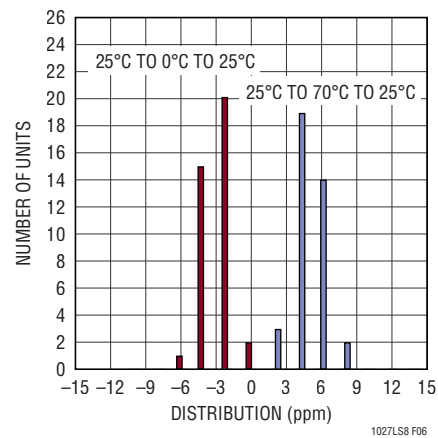


Figure 6. Thermal Hysteresis Plot, 0°C to 70°C

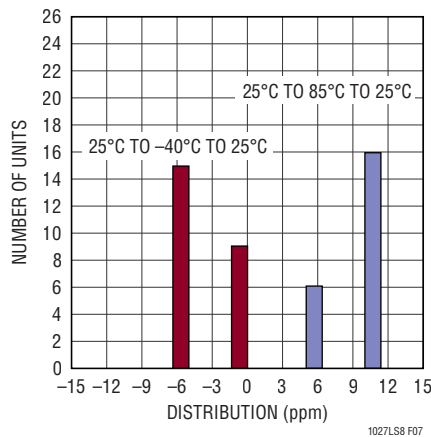


Figure 7. Thermal Hysteresis Plot, -40°C to 85°C

## TYPICAL APPLICATIONS

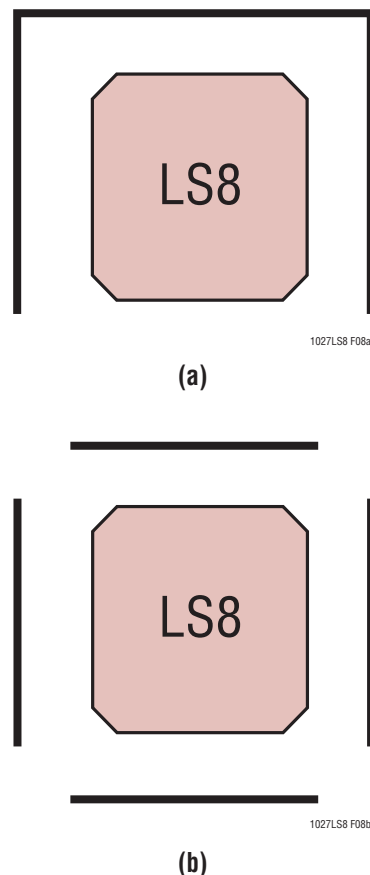
### Humidity Sensitivity

Plastic mold compounds absorb water. With changes in relative humidity, plastic packaging materials change the amount of pressure they apply to the die inside. These pressure changes can cause slight changes in the output of a voltage reference, usually on the order of 100ppm. The LS8 package is hermetic, so it is not affected by humidity, and is therefore more stable in environments where humidity may be a concern. However, PC board material may absorb water and apply mechanical stress to the LT1027LS8. Proper board materials and layout are essential.

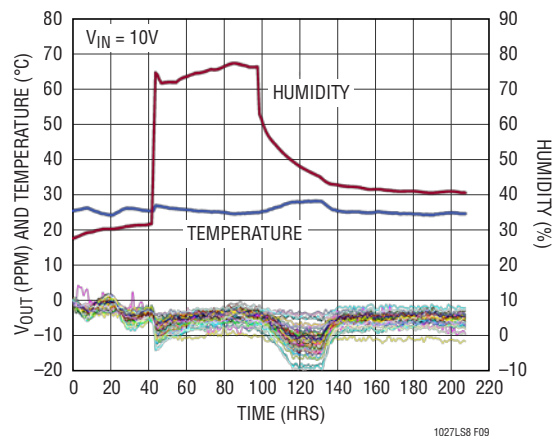
For best stability, the PC board layout is critical. Change in temperature and position of the PC board, as well as aging, can alter the mechanical stress applied to components soldered to the board. FR4 and similar materials also absorb water, causing the board to swell. Even conformal coating or potting of the board does not always eliminate this effect, though it may delay the symptoms by reducing the rate of absorption.

Power and ground planes should be omitted under the voltage reference IC for best stability. Figure 8a shows a tab cut through the PC board on three sides of an LT1027LS8, which significantly reduces stress on the IC, as described in Application Note 82. For even better performance, Figure 8b shows slots cut through the PC board on all four sides. The slots should be as long as possible, and the corners just large enough to accommodate routing of traces. It has been shown that for PC boards designed in this way, humidity sensitivity can be reduced to less than 35ppm for a change in relative humidity of approximately 60%. Mounting the reference near the center of the board, with slots on four sides, can further reduce the sensitivity to less than 10ppm.

An additional advantage of slotting the PC board is that the LT1027LS8 is thermally isolated from surrounding circuitry. This separation can help reduce thermocouple effects and improve accuracy.



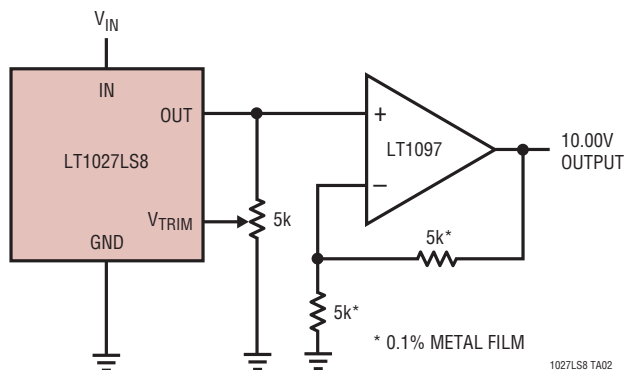
**Figure 8. (a) 3-Sided PCB Tab Cutout, (b) 4-Sided PCB Cutout. Lines Represent Cuts All the Way Through the PCB**



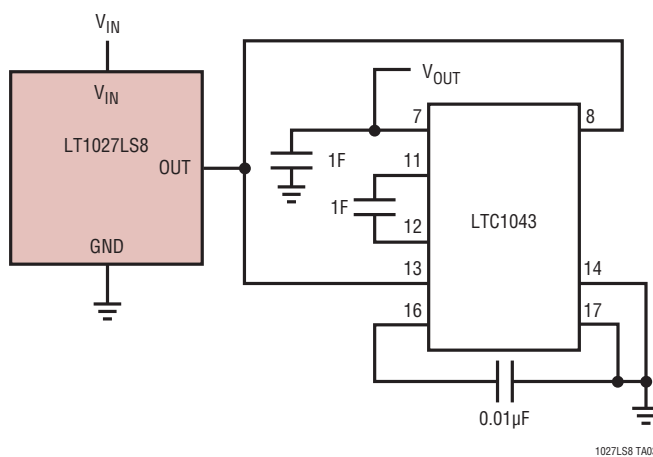
**Figure 9. Illustrates Drift of LT1027LS8 with Large Changes in Humidity. Using Proper PCB Layout Techniques Limits This Drift to a Few ppm**

## TYPICAL APPLICATIONS

10V Reference

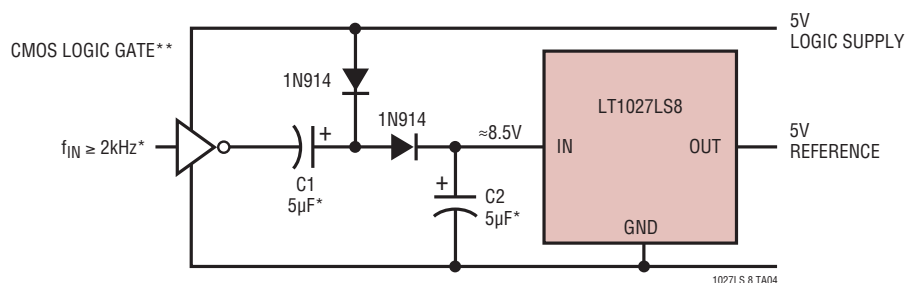


10V Reference



## TYPICAL APPLICATIONS

### Operating 5V Reference from 5V Supply

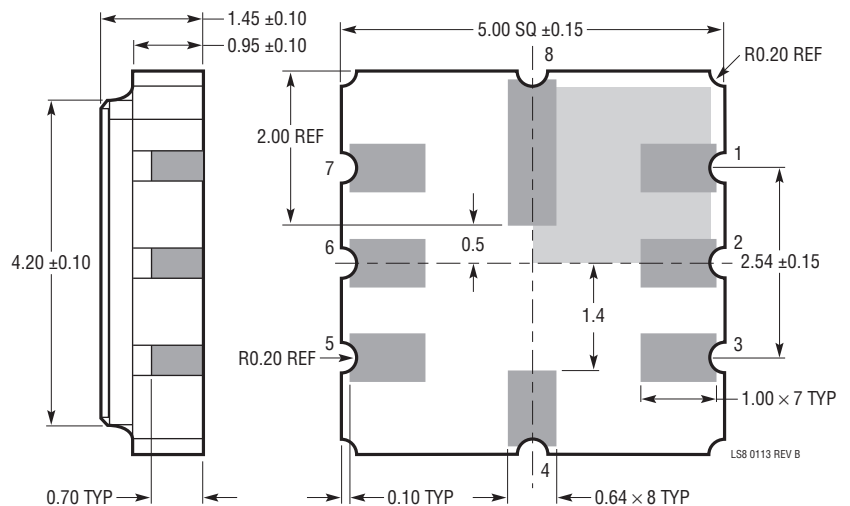
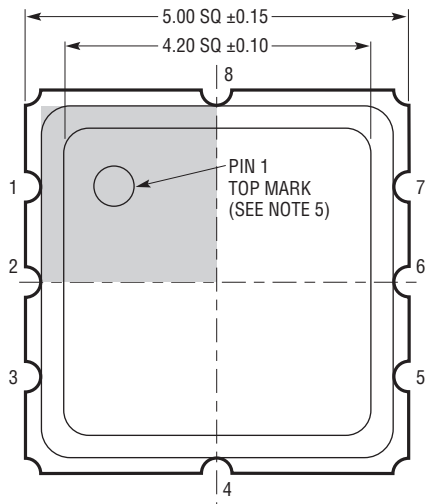
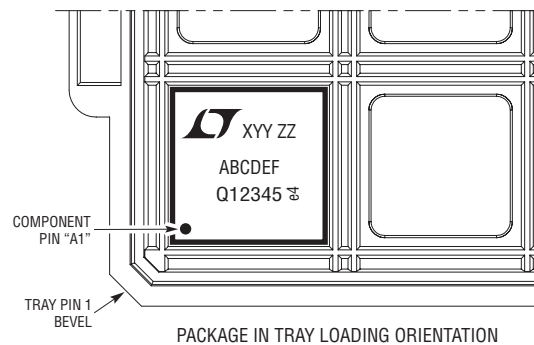
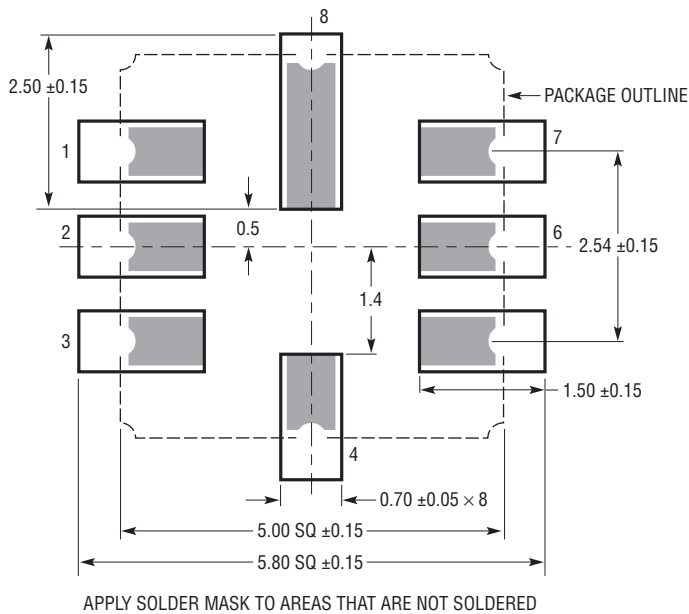


\*FOR HIGHER FREQUENCIES C1 AND C2 MAY BE DECREASED  
 \*\*PARALLEL GATES FOR HIGHER REFERENCE CURRENT LOADING

# PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/product/LT1027LS8#packaging/> for the most recent package drawings.

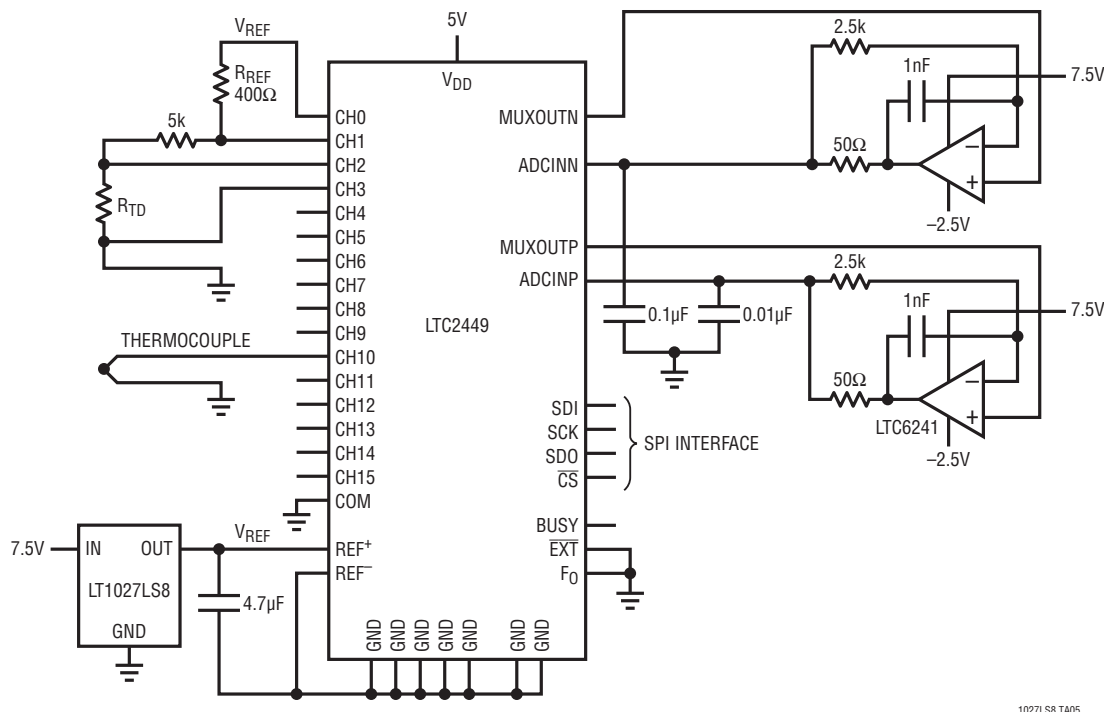
## LS8 Package 8-Pin Leadless Chip Carrier (5mm × 5mm) (Reference LTC DWG # 05-08-1852 Rev B)



- NOTE:
1. ALL DIMENSIONS ARE IN MILLIMETERS
  2. DRAWING NOT TO SCALE
  3. DIMENSIONS PACKAGE DO NOT INCLUDE PLATING BURRS  
PLATING BURRS, IF PRESENT, SHALL NOT EXCEED 0.30mm ON ANY SIDE
  4. PLATING—ELECTO NICKEL MIN 1.25UM, ELECTRO GOLD MIN 0.30UM
  5. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

## TYPICAL APPLICATION

### Precision Temperature Sensor



## RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1021	Precision References for Series or Shunt Operation in Hermetic TO-5, SOP-8, DIP-8 Package	0.05% Max Initial Error, 5ppm/°C Max Drift, 1ppm Peak-to-Peak Noise (0.1Hz to 10Hz), -55°C to 125°C (TO-5)
LT1236	Low Drift, Low Noise, 5V and 10V Voltage Reference in SO8, DIP8 and LS8 Packages	0.05% Max Initial Error, 5ppm/°C Max Drift, 1ppm Peak-to-Peak Noise (0.1Hz to 10Hz), -40°C to 85°C
LT1236LS8	Precision Series Reference, 0.05%, 5ppm/°C Drift	Low Profile Hermetic LS8 Package
LTC®6652	High Precision, Buffered Voltage Reference Family in MSOP8 and LS8 Package	0.05% Max Initial Error, 5ppm/°C Max Drift, Shutdown Current <2µA, -40°C to 125°C Operation
LT6654	Precision, Low Noise, High Output Drive Voltage Reference Family in MSOP8 and LS8 Package	1.6ppm Peak-to-Peak Noise (0.1Hz to 10Hz) Sink/Source ±10mA, 5ppm/°C Max Drift, -40°C to 125°C Operation
LTC6655	Exceptional Low Noise, High Precision Reference in MSOP8 and LS8 Package	0.25ppm Peak-to-Peak Noise (0.1Hz to 10Hz), 2ppm/°C Maximum Drift, 0.025% Maximum Initial Error, -40°C to 125°C Operation